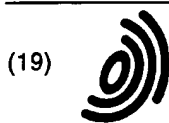


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**(54) Organic light emitting device and preparation and use thereof**

Organisches lichtemittierendes Bauelement sowie dessen Herstellung und Verwendung

Dispositif émetteur de lumière organique, ainsi que sa préparation et son usage

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(56) References cited:  
**EP-A- 0 218 422**

- **APPLIED PHYSICS LETTERS** vol. 51, no. 12, 21 September 1987, pages 913-915, New York, US; C.W. TANG et al.: "Organic electroluminescent diodes"
- **CHEMICAL ABSTRACTS** vol. 110, no. 6, 1989, page 20, left-hand column, abstract no. 39651c, Columbus, Ohio, US; G.V. KAPUSTIN et al.: "Exiplex nature of luminescence in some aromatic polyimides"
- **JOURNAL OF MOLECULAR ELECTRONICS** vol. 5, no. 1, March 1989, pages 63-70, Chichester, GB; A.V. VANNIKOV et al.: "Solar energy conversion based on polymers"
- **Idem**
- **APPLIED PHYSICS LETTERS** vol. 54, no. 10, 6 March 1989, pages 872-874, New York, US; Y. KANEMITSU et al.: "Photocarrier generation and injection at the interface in double-layered organic photoconductors"
- **SOVIET PHYSICS USPEKHI** vol. 31, no. 7, July 1988, pages 623-644, New York, US; L.M. BLINOV: "Langmuir films"

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**EP 0 470 629 B1**

**Description**Field of the Invention

5 The present invention relates to an organic light-emitting device such as a spatial light modulator, a light neural network device and etc. used for an optical computing device and a light emitting type display, a method for preparing the same.

Description of the Related Art

10 The light-emitting device generally includes 1) a light emitting display device constituting a light-emitting layer between a lower electrode on a base plate and an upper electrode, 2) an electric field light emitting device constituting a light emitting layer laminated on a carrier transport layer supported by a base plate and 3) a spatial light modulator type device constituting a lower electrode on a base plate and light-emitting layer, a carrier transport layer and a transparent electrode which are laminated in turn on the lower electrode.

15 Recently, it is reported that a preparation trial of an organic light emitting device was made by using an organic compound as a necessary constituent. For example, the L256 page of Japanese Journal of Applied Physics 27(2)(1988) discloses an electric field light emitting device having a laminated structure provided with an organic light emitting layer and a carrier transport layer as the above type 2). In the device, a semi-transparent lower electrode of Au is mounted on a glass base plate and thereon are mounted in turn many layers, which are a hole transport layer of N,N'-diphenyl-N,N'-(3-methylphenyl)-1,1'-biphenyl-4,4'-diamine (hereinafter referred to as TPD) having a 200 nm coating, an organic light emitting layer and an electron transport layer of perylene-tetra carboxyl group derivatives, the latter two layers being 100 nm coating in thickness.

25 Further, the upper electrode comprises Mg coating. A bright light emission was observed by applying an electrostatic field to the lower and upper electrodes when phthaloperynone derivatives is used as a material of the organic light emitting layer (see the preprint for the 35th Spring Lecture Meeting of the Applied Physics Society). The emitting light can be varied depending on a material of the organic light emitting layer to be selected.

30 Further, as to the above type 3) it is reported that another organic light emitting device constituted by using an amorphous alloy of  $\text{Si}_{1-x}\text{C}_x\text{H}$  as a light emitting type spatial light modulator used for an optical computing device and so on (see the preprint for the 37th Spring Lecture Meeting of the Applied Physics Society).

35 In the reported device, lamination of a carrier transport layer and a light emitting layer make the number of electron inplating increased and thus make luminous efficiency thereof improved in comparison of the convenient organic light emitting device, but the efficiency is below 0.5% and more development is needed. Further, change with time of luminous brightness is large and especially there comes to arise problems such as lowering of electron inplating efficiency for the light emitting layer and accumulation of spatial carrier in the carrier transport layer.

The lowering of luminous brightness is caused by the following factors:

- 1) quenching caused by crystallization of the molecule constituting light emitting layer.
- 2) decomposition of the molecule constituting a light emitting layer caused by the reaction thereof with oxygen molecule and so on.
- 3) obstruction of electron inplating from outside caused by the accumulation of carrier in the light emitting layer.

45 A light emitting element comprising a double layer of organic thin films is described in the article "Organic electroluminescent diodes" by Tang and VanSlyke in Applied Physics Letters, vol. 51, no. 12, pages 913-915. A selection of polymers and polymeric composites used in photovoltaic structures is disclosed in the article "Solar Energy Conversion Based on Polymers" by Vannikov and Zhuravleva in Journal of Molecular Electronics, vol. 5, no. 1 pages 63 to 70.

SUMMARY OF THE INVENTION

50 To solve the aforementioned problems of the prior arts, the first object of the present invention is to provide an organic light emitting device having an ability of high brightness and small change with time of the luminous brightness.

The second object of the present invention is to provide an organic light emitting device having at least a carrier transport layer and a light emitting layer between an upper electrode and a lower electrode mounted on a base plate.

55 The third object of the present invention is to provide an organic light emitting device having a carrier transport layer, a light receiving layer and a light emitting layer used for a light neural network device.

The fourth object of the present invention is to provide a process for preparing the organic light emitting device.

To achieve the above objects, there is provided a light emitting device comprising an organic light-emitting layer according to Claim 1, a process for its preparation according to Claim 6, and its use according to Claim 5. Said organic

light-emitting layer contains a polymer comprising a repeating unit of the formula:



wherein n is at least 2, X is O, S, Se or Te, Y is an aromatic or substituted aromatic group, Z is a group containing an imide ring.

In a preferred embodiment a carrier transport layer is constituted of a polymer represented by the following formula:



wherein n is at least 2, X is O, S, Se or Te, Y is an aromatic or substituted aromatic group.

In the present invention, there are provided the following functions and effects:

1. As a light emitting layer is made of a polymer layer containing a repeating unit of the formula (I), the light emitting layer is incorporated into a backbone of main chain or a side chain of a heat resistive polymer and the Z group functioned as a light emitting part is dispersed by the molecular level in a matrix not to be coagulated with each other. Thereby, there is provided an organic light emitting device having an ability of high brightness and small change with time of luminous brightness. Further, the Y group of the formula (I) has a superior ability of carrier transport in the layer, thus little carrier accumulation is observed in the layer.

2. According to the preferred embodiment wherein a light emitting layer comprises a polymer of the formula (I) and is laminated with another light receiving layer, there is provided a more improvement of luminescent efficiency.

3. According to the process for preparing an organic light emitting device wherein a polymer containing a repeating unit of the formula (I) is laminated on the base plate by a gas-liquid boundary developing growth method, there is provided a thin and no defective coating. A light emitting portion of the light emitting layer is limited in a neighbourhood of the boundary between the light emitting layer and another carrier transport layer or the electrode. Therefore, it is advantageous to form a light emitting layer thin to a degree of having no pin-hole. Further, it is advantageous that the thin layer can lower a driving voltage. Especially, it is preferable that the polymer represented by the formula (I) is laminated on the base plate by a LB method (Langmuir-Blodgett's technique), in that there can be provided a polymer layer having a few atomic layer thickness and no pin-hole.

4. According to the light emitting device used for an optical neural network device comprising a lower electrode on a base plate and thereon laminating a light receiving layer, a light emitting layer containing a polymer of the repeating unit of the formula (I), a carrier transport layer and a transparent electrode in turn, the device comes to have an exact recognizing ability.

5. A polymer containing a repeating unit of the formula (II) has a high carrier transport ability and a high optical sensitivity. It is found by us that an increasing crystallinity of the polymer leads to a remarkable increasing sensitivity. In the organic light emitting device, the amorphous of the carrier transport layer is the largest cause for lowering of the carrier transport efficiency into the light emitting layer and accumulation of the space charge in the carrier transport layer. The reason that the carrier transport layer is an amorphous is to realize to form a layer having a thin thickness and no pin hole in order to provide a device having a light emitting ability by means of a low voltage. However, that necessarily make a carrier trap density increased and thus a carrier mobility does not become large. On the other hand, it is advantageous that the polymer comprising a repeating unit of the formula (II) is a crystalline and provide a layer having no pin hole.

6. In the case that a wavelength of the emitting light from the organic light emitting device is shorter than that of the absorbing light, the device provides a memory ability. That is caused by that the polymer layer contributes to the absorbing light as a carrier emitting layer.

7. The polymer comprising a repeating unit of the formula (II) is effective to use of a light receiving layer of a spatial light modulator. The electron implanting efficiency between an inorganic light sensitive layer represented by an amorphous alloy of the formula  $Si_xC_x$  and an organic light emitting layer is depended on a work function difference. On the other hand, the electron implanting efficiency between the polymer layer and an organic light emitting layer is as high as the boundary bonding condition therebetween.

#### BRIEF DESCRIPTION OF THE DRAWINGS

Fig. 1, 2 and 3 are cross sections of three examples of the light emitting device according to the present invention. Fig. 4 is a schematic view of an accumulation apparatus for carrying a LB method to prepare the light emitting device according to the present invention.

Fig. 5 shows the voltage-current characteristic of Example 1.

Fig. 6 shows the current-luminous brightness characteristic of Example 1.

Fig. 7 shows the luminous spectrum of the organic light emitting device according to the present invention.

Fig.8 shows the current-luminous brightness characteristic of Example 2.

Fig.9 shows the voltage-luminous brightness characteristic of Example 3.

Fig.10 shows the memory property of Example 3.

Fig.11 shows the change of luminous brightness relating to the incident light intensity.

Fig.12 is a schematic view of the optical neural network system.

Fig.13 shows the voltage-current characteristic of Example 6.

Fig.14 shows the current-luminous brightness characteristic of Example 6.

Fig.15 is a schematic view of the vacuum depositing apparatus for preparing the organic light emitting device according to the present invention.

Fig.16 shows the current-luminous brightness characteristic of Example 7.

Fig.17 shows the voltage-luminous brightness characteristic of Example 8.

Fig.18 shows the memory property of Example 8.

Fig.19 shows the change of luminous brightness relating to the incident light intensity in Example 9.

Fig.20 shows the memory property to the incident light of the organic light emitting device in Example 9.

## DETAILED DESCRIPTION OF THE INVENTION

Referring now to the drawings, embodiments of the present invention will be explained in detail.

Fig.1 is a sectional view of a first embodiment of the organic light emitting device used for an electric display device. In the device, on a transparent insulating base plate (for example, made of glass) 101 there is mounted a transparent electroconductive electrode 102 (for example, made of ITO or  $\text{SnO}_x$ ) and an organic light emitting layer 103 is laminated thereon. On the light emitting layer 103, an upper electrode 104 is mounted. Between the electroconductive electrode 102 and the upper electrode 104, there is applied a DC or AC electric field as an outer voltage. The organic light emitting layer 103 is preferably 0.5 to 500 nm in thickness.

Fig.2 is a sectional view of a second embodiment of the organic light emitting device used for an electric display device. In the device, on a transparent insulating base plate (for example, made of glass) 201 there is mounted a transparent electroconductive electrode 202 (for example, made of ITO or  $\text{SnO}_x$ ) and a carrier transport layer 203 and an organic light emitting layer 204 are laminated thereon. On the light emitting layer 204, an upper electrode 205 is mounted. Between the electroconductive electrode 202 and the upper electrode 205, there is applied a DC or AC electric field as an outer voltage. Another carrier transport layer may be provided between the organic light emitting layer 204 and the upper electrode 205. The organic light emitting layer 204 is preferably 10 nm to 5  $\mu\text{m}$  in thickness.

Fig.3 is a sectional view of a third embodiment of an organic light emitting device, used for a spatial light modulator and a light neural network device. In the device, on an insulating base plate 301 there is mounted a lower electrode 302 and a light receiving layer 303 and an organic light emitting layer 304 are laminated thereon. On the light emitting layer 304, a carrier transport 305 and an transparent upper electrode 306 are further mounted. The lower electrode may be a transparent electroconductive electrode. Between the lower electrode 302 and the upper electrode 306, there is applied a DC or AC electric field as an outer voltage.

If a light from the light emitting layer is received by the organic light receiving layer in the case of Fig.3, the light emitting device provides a memory ability characteristic. On the other hand, if the lower electrode 302 is a transparent electroconductive electrode and a light through the lower electrode 302 is irradiated from outside to the organic light receiving layer 303, the device provides an ability of a light emitting type spatial light modulator.

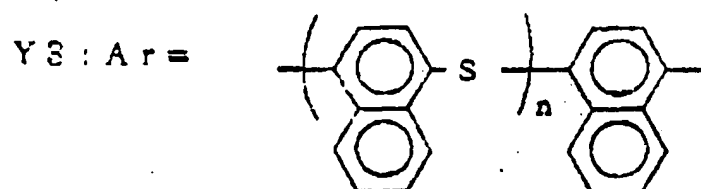
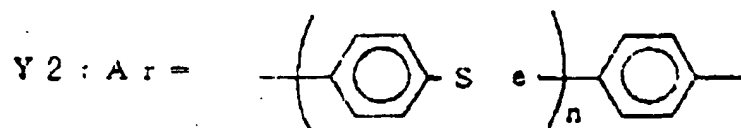
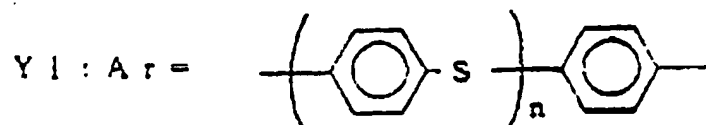
Now, the polymer containing a repeating unit of the formula (I) and (II) of the present invention will be explained in detail.

The polymer used for the present invention comprises the repeating units of the formula:



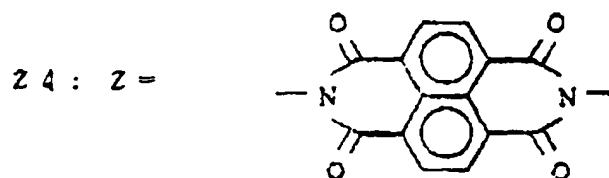
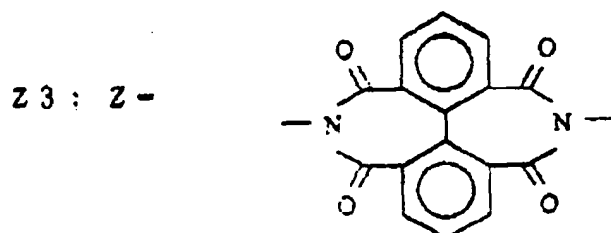
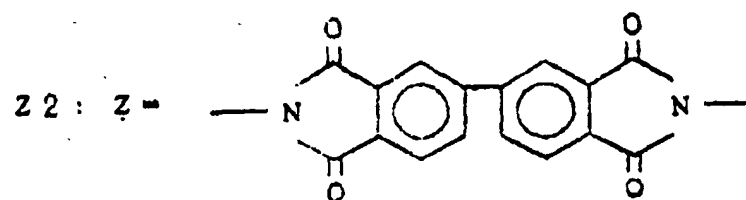
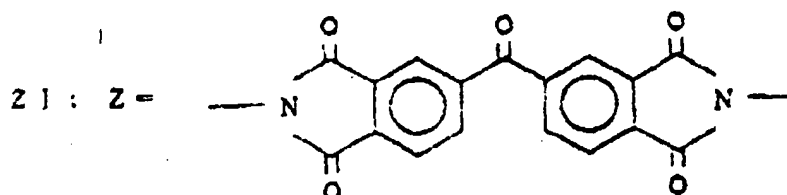
In the formula (I), n is a number of at least 2 and X is O, S, Se or Te. Y is an aromatic or substituted aromatic group and Z is a group including an imide ring.

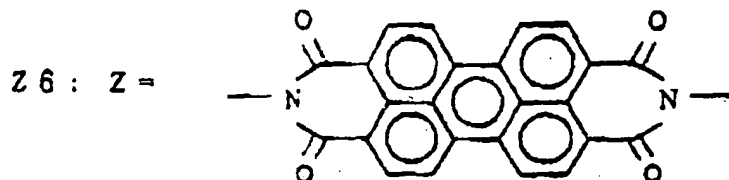
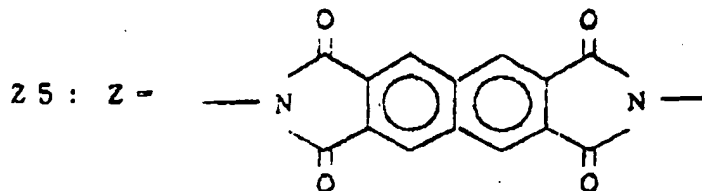
The Y group examples include condensed polycyclic hydrocarbons and their substituted derivatives (e.g. anthracene, naphthalene, pyrene, perylene, naphthacene, benzoanthracene, benzophenanthrene, crycene, triphenylene, phenanthrene, etc), condensed polycyclic quinones (e.g. anthraquinone, dibenzopyrenequinone, anthroanthrone, isoviolanthrone, pyranthrone, etc.). Among their examples, Y group of the formula (I) is preferably selected from the following group examples:



wherein n is preferably from 1 to 5.

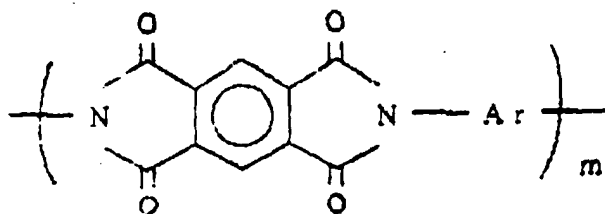
The Z group examples include any group including an imide ring, preferably selected from the following examples:



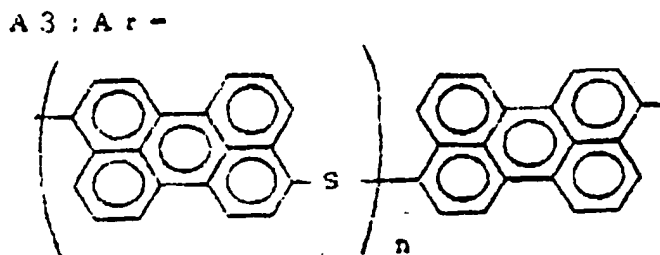
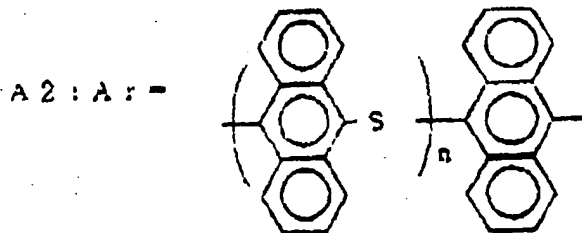
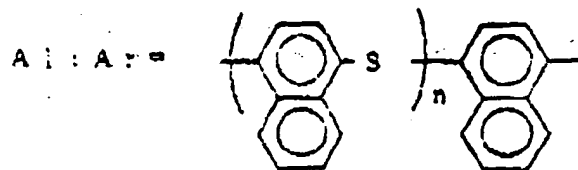


15      As the representative examples corresponding to three original colour, the Y group of the formula (I) includes perylene (orange), coronene (green) and anthracene (blue).

20      Examples of the organic polymer comprising the repeating unit of the formula (I) are polyimide, polyamide imide, polyamide, polyether amide, polyester, polyester imide, polyester amide and the like. Among their examples, the following examples are preferred.



30      wherein m is preferably from 10 to 10,000.



50      wherein n is preferably from 1 to 5.

55      The polymer used for the invention has a weight (or number) average molecular weight of  $10^2$  to  $10^5$ , preferably

$10^3$  to  $5 \times 10^4$ .

The organic molecule of the formula (I) may constitute a backbone or a side chain of the polymer.

The polymer used for a carrier transport layer and an organic light receiving layer comprises the repeating units of the formula:



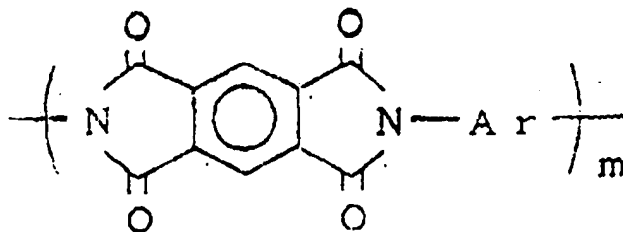
In the formula (II),  $n$  is a number of at least 2 and  $X$  is O, S, Se or Te.  $Y$  is an aromatic or substituted aromatic group, and their examples include condensed polycyclic hydrocarbons and their substituted derivatives (e.g. benzene, anthracene, naphthalene, pyrene, perylene, naphthacene, benzoanthracene, benzophenanthrene, crycene, triphenylene, phenanthrene, etc.), condensed polycyclic quinones and their substituted derivatives (e.g. anthraquinone, dibenzopyrenequinone, anthoanthrone, isoviolanthrone, pyranthrene, etc.), metal-free phthalocyanine, metal phthalocyanines (containing a metal such as copper, lead, nickel, aluminum and the like) indigo, thioindigo and their derivatives.

Examples of the organic polymer comprising the repeating unit of the formula (II) are polyimide, polyamide imide, polyamide, polyether amide, polyester, polyester imide, polyester amide and the like. The polymer used for the invention has a weight (or number) average molecular weight of  $10^2$  to  $10^5$ , preferably  $10^3$  to  $5 \times 10^4$ .

Among their examples, the following examples are preferred.

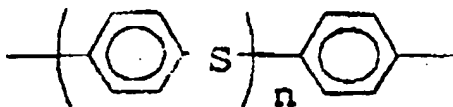
The organic molecule of the formula (II) may constitute a backbone or a side chain of the organic polymer.

Among the following examples, A1 to A12 are copolymers in which the organic polymer is polyimide. In A1 to A6, an acid component of polyimide is pyromellitic acid. In the formula (II),  $X$  is S, and  $Y$  is benzene ring in A1;  $X$  is Se, and  $Y$  is benzene ring in A2;  $X$  is S, and  $Y$  is naphthalene ring in A3;  $X$  is S, and  $Y$  is anthracene ring in A4;  $X$  is S, and  $Y$  is perylene ring in A5;  $X$  is S, and  $Y$  is 2,5-dichlorobenzene ring in A6;

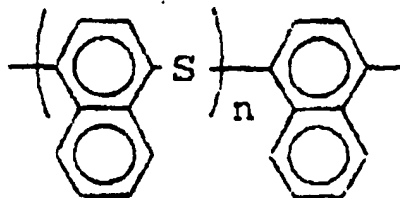


wherein  $m$  is preferably from 10 to 10,000.

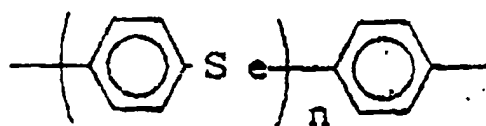
(A1) Ar =



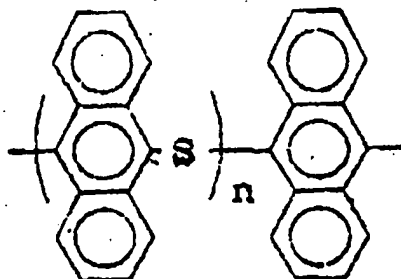
(A2) Ar =



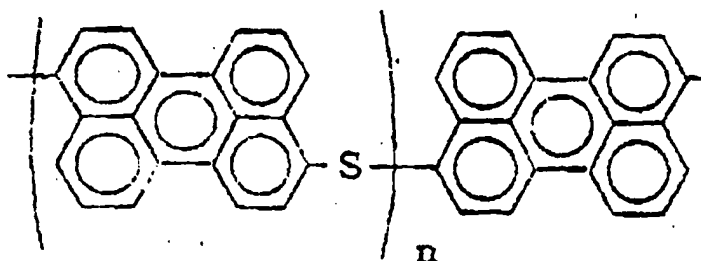
(A 3) Ar =



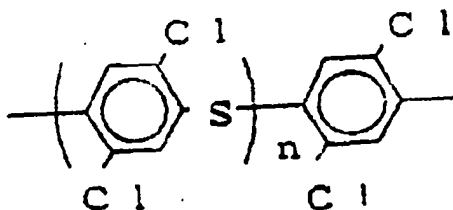
(A 4) Ar =



(A 5) Ar =



(A 6) Ar =



The examples A7 to A12 are similar to A1 but n is fixed at 2, and as an acid component of polyimide, is used

3,3',4,4'-benzophenonetetracarboxylic dianhydride in A7;

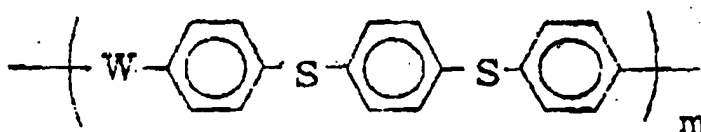
3,3',4,4'-biphenyltetracarboxylic dianhydride in A8;

1,1',5,5'-biphenyltetracarboxylic dianhydride in A9;

naphthalene-1,4,5,8-tetracarboxylic dianhydride in A10;

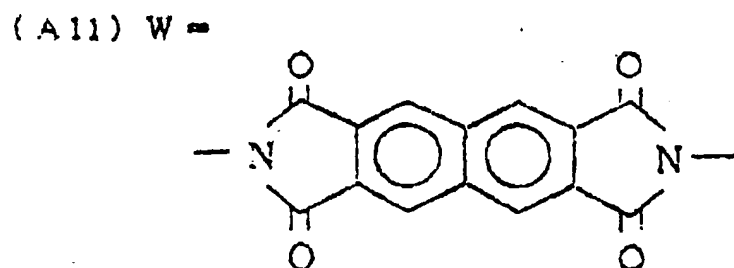
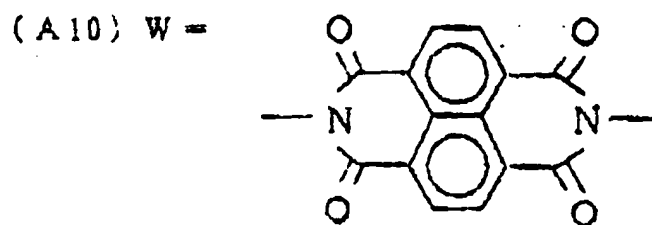
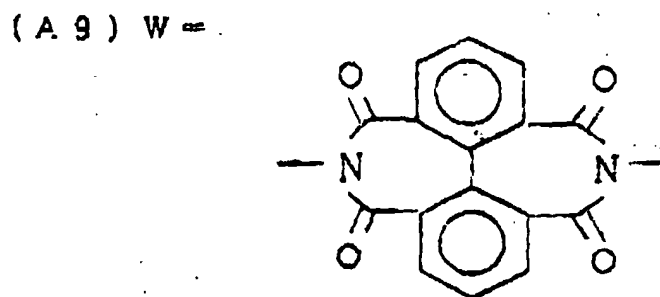
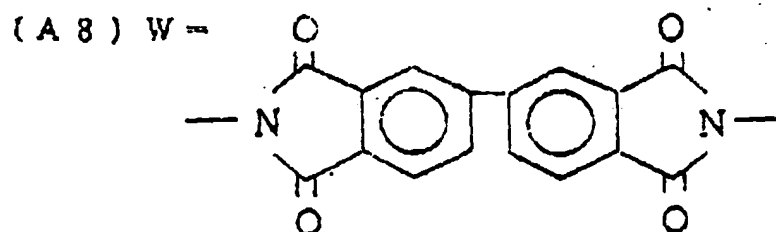
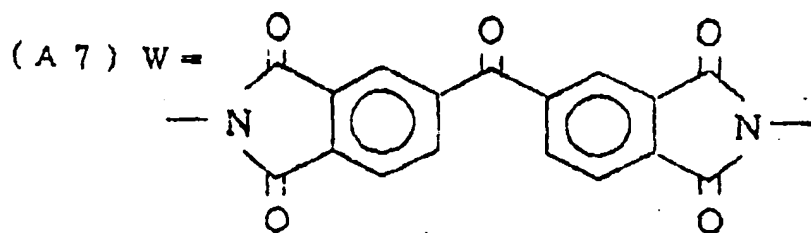
naphthalene-2,3,6,7-tetracarboxylic dianhydride in A11;

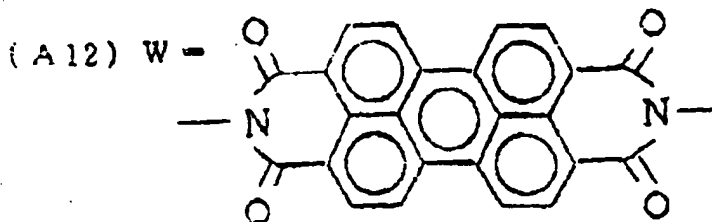
or perylene-3,4,9,10-tetracarboxylic dianhydride in A12.





wherein m is preferably from 10 to 10,000.





The above polyimide may be prepared by any of conventional polymerization methods. For example, a tetracarboxylic dianhydride as an acid component and a diamine compound which is represented by the formula (I) and (II) having amine groups at both ends are reacted in an organic polar solvent (e.g. N,N'-dimethylacetamide, 1-methyl-2-pyrrolidinone, N,N'-dimethylformamide, m-cresol, etc.). Especially, a preferred available process for preparing the above polymer is disclosed in US serial No.673,759 (filed March 25, 1991).

In a process for preparing the organic light emitting device, there may be used a coating method, a vacuum deposition method, a molecular beam epitaxy (MBE), an ionized cluster method and etc. for forming an organic light emitting layer, a carrier transport layer and a light receiving layer by using the polymer as well as a method of gas-liquid boundary developing growth. The method of gas-liquid boundary developing growth includes a LB method. Among their methods, a LB method is most preferred, because a thin and no pin hole layer can be formed on a desired surface. In the LB method, conventional technics may be applied.

The present invention will be illustrated by the following examples.

#### Example 1

In the organic light emitting device shown in Fig.1, a transparent insulating base plate 101 is made of glass base plate and thereon a transparent electroconductive electrode 102 is formed as an Indium Tin Oxide(ITO) layer of 0.1 to 0.5  $\mu\text{m}$  in thickness by means of sputtering. As an organic light emitting device 103, a polymer A2 having a light emitting part of anthracene is laminated by a LB method as a example of a gas-liquid boundary developing growth while a spin coating method is used for forming the layer. The following description explains a process for forming a layer by the LB method.

Fig.4 is a schematic view of an accumulation apparatus for carrying a LB method. In Fig.4, 401 denotes a LB apparatus, 402 is a tank for developing pure water, 403 is a base plate and 404 is a weight.

Diamine compound having an anthracene group as a light emitting part and pyromellitic acid anhydride of an aromatic tetracarboxylic acid dianhydride are added in the ratio 1:1 to organic solvent of dimethyl acetamide and polymerized to obtain a polyamide acid. The polyamide acid is diluted with a mixture solvent (1:1) of dimethylacetamide and benzene to 1 mmol/l. The polyamide acid is controlled with C16DMA in the ratio 1:2 just before the mixture is developed at the boundary of gas and water.

The accumulation condition of polyamide acid monomolecular film is a surface pressure of 25 dyn/cm<sup>2</sup>, a pulling up speed of 3 to 10 mm/min and a room temperature of 20. A resultant film of 10 nm in thickness is obtained by 20 times of developing.

Finally, polyamide accumulation film is imidized by a chemical imidation method. A base plate is dipped into a mixture of acetic anhydride, pyridine and benzene (1:1:3) for 12 hours to form a polyimide accumulation film thereon and washed with benzene to remove the solvent.

The resultant device is tested as to the electric and light emitting properties. In the test, a DC voltage is applied between the transparent electrode 102 and the upper electrode 104. The voltage-current characteristic is shown in Fig.5 and the current-luminous brightness characteristic in Fig.6. At more than 5 V of the applied DC voltage, the current density becomes more than 100 mA/cm<sup>2</sup> and at the same time the brightness begins to be beyond 100 cd/m<sup>2</sup>. At 10 V of the applied voltage, the luminous brightness of about 500 cd/m<sup>2</sup> is obtained.

In the place of anthracene as a group of the light emitting part, each polymer coating having a naphtharene, pyrene and perylene group is formed. Each of emission spectrum at 10 V of applied voltage is shown in Fig.7.

#### Example 2

In the organic light emitting device shown in Fig.2, on a transparent insulating base plate 201 made of glass base plate there is formed ITO layer of 0.1 to 0.5  $\mu\text{m}$  in thickness as a transparent electroconductive electrode 202 by means of sputtering and formed an carrier transport layer 203. As a material of the carrier transport layer 203, a polyimide (hereinafter referred to as BPDA-Phn wherein n is defined as below), which is polymerized from benzophenonetetracar-

boxylic dianhydride (hereinafter referred to as BPDA) and oligo p-phenylenesulfide diamine (hereinafter referred to as SDA-n, which is represented by the formula:  $\text{NH}_2\text{-A-NH}_2$  wherein A:  $-(\text{Ph-S})_{n-1}\text{-Ph-}$ ;  $n=2,3,4,5$ ) is used. In the synthesis of a polyamic acid as a precursor of the polyimide, BPDA and SDA-n are polymerized in a solvent of dimethylacetamide. The polyamic acid is coated by a thickness of 50 to 200 nm on the base plate surface by means of spinner. After application, the base plate is heated for 2 hours at 300°C in a furnace. In this process the polyimide film is imidized and crystallized. As an organic light emitting layer, the polymer A2 is formed by a degree of 5 atomic layers by means of the same method of Example 1.

The resultant device is tested as to the electric and light emitting properties. In the test, a DC voltage is applied between the transparent electrode 202 and the upper electrode 205. The voltage-current characteristic is shown in Fig.8 and the current-luminous brightness characteristic in Fig.9. At more than 7 V of the applied voltage, the current density becomes more than 100 mA/m<sup>2</sup> and at the same time the brightness begins to be beyond 100cd/m<sup>2</sup>. At 10 V of the applied voltage, the luminous brightness of about 500 cd/m<sup>2</sup> is obtained.

#### Example 3

A light emitting device having an organic light receiving layer of polyimide with an ability of memory is prepared. A device structure is shown in Fig.3. As a lower electrode 302, ITO is formed on a glass base plate 301 and thereon BPDA-Ph3 (BPDA-Phn wherein  $n=3$ ) of 2  $\mu\text{m}$  in thickness is formed as a light receiving layer 303 by means of a method of example 2. A light emitting layer 304 is formed by the polymer A2 comprising anthracene having an emission peak wavelength of 480 nm and the polymer A1 comprising naphthalene having a emission peak wavelength of 460 nm. BPDA-Ph3 has a sensitive region shorter than 550 nm. A upper transparent electrode 306 is formed with ITO at a room temperature.

The applied voltage-luminous brightness characteristic is shown in Fig.10. The brightness property shows hysteresis. That is, at 40 V of applied voltage it comes to be in a light emitting state and keep such a light emitting state until less than 20 V of applied voltage.

#### Example 4

In a structure of the organic light emitting device of example 2, a full colour display is prepared by using 3 original colour, as picture components, comprising the polymer A2 having anthracene group as a blue light emitting part, the polymer having pyrene group as a green light emitting part and the polymer having perylene group as a red light emitting part.

This image display apparatus provides more than 1000 hours of half life at 50 % of the luminous brightness. The energy transfer efficiency is 1.0 to 3.3%. According to the present invention, there is provided a high bright multicolour display having a long life and an ability of stable driving at a low voltage.

#### Example 5

A spatial light modulator device of light emitting type is prepared. The device structure is same as Example 3. In this case, a light receiving layer 303 is light-written by means of incident light from a glass base plate 301. The incident light is a semiconductor laser (780nm). As a light receiving layer sensitive to this wavelength, a polyimide layer containing 2 wt.% of non-metallic phthalocyanine is formed by an almost same method as Example 3. A light emitting layer 304 is formed of the polymer having a emission peak of 480 nm by a method similar to Example 3. A change of the luminous brightness relating to an intensity of incident light is shown in Fig.11. It shows a non-linear property and a memory property. That is, A part in a state of light emitting by means of light-writing is maintained after incident light disappears. When incident light is irradiated at 35 V of applied voltage, a voltage drop occurs in the light receiving layer and thus electric field is concentrated to the light emitting layer 304 and thereby light is emitted. Without an incident light, the light receiving layer keep a low resistance condition by means of irradiation from the light emitting layer and thus the light emitting state is maintained. When the applied voltage becomes less than 5 V, the device enter into quenching state and even if the voltage returns to the primary voltage of 35 V, the light receiving layer 203 becomes a high resistance condition and the quenching is maintained.

An optical neural network system is constituted by using the light emitting device and a test for its function and operation is carried. The device structure is shown in Fig.12. The system is operated on the basis of an orthogonal learning method and is constituted of an incident picture 111 comprising the light emitting device of Example 1, a microlens array 112, a learning mask pattern 113 and an optical threshold device 114. The incident picture 111 has a matrix of 6x6 and can indicate 10 words of alphabet. As a picture input, a memory ability is used and each picture element is electrically written. The learning mask pattern 113 comprises a matrix of 36x36 and a variety of transmissivity in order to indicate 8 gradients depending on the intensity of transmitted light. The optical threshold device 114 comprises a

matrix of 6x6, in which a transmitted light is condensed from 6x6 of mask patterns to each picture element through the microlens array 113. The light emitting is made according to a light non-linear manner shown in Fig.9. The system make answers with a recognition rate of 100% to a self-imagination of perfect pattern provided alphabet 10 words and an association of imperfect pattern provided with a hamming distance of 1.

As explained above, according to the embodiment of the present invention, a picture indication device comprising a light emitting device having a light emitting layer containing a polymer of the formula (I) makes it possible to realize a high brightness display provided with a long life and stable driving at a low voltage and also realize a spatial light modulator having an ability of light-writing by means of light irradiation from outside. Therefore, the device is preferred to an optical computing system including an optical neural network system as a representative device or system.

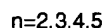
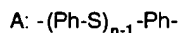
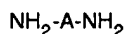
#### Example 6

In the organic light emitting device shown in Fig.2, polyimide (BPDA-Phn) as a polymer including a repeating unit of the formula (II), which is polymerized by BPDA and SDA-n, is used as the material of a carrier transport layer 103. A polyamic acid as a precursor of the polyimide is synthesized by BPDA and SDA-n in a solvent of dimethylacetamide (DMAc). The polyamic acid is applied to the surface of the above glass base plate with a thickness of 50 to 200 nm by spinning. The glass base plate is heated for 2 hours at 300°C in a furnace after the application. The polyimide film is imidized and crystallized in this process. As an organic light emitting layer, 8-quinolinol aluminum complex (Alq<sub>3</sub>) is formed from 20 to 50 nm by a vacuum deposition. The upper electrode 205 is formed with MgIn by the same vacuum depositing.

The resulting device is tested as to the electric and light emitting properties. In the test, a DC voltage is applied between the transparent electrode 202 and the upper electrode 205. The voltage-current characteristic is shown in Fig.13 and the current-luminous brightness characteristic in Fig.14. At more than 20 V of the applied DC voltage, the current density becomes more than 100 mA/m<sup>2</sup> and at the same time the brightness begins to be beyond 100 cd/m<sup>2</sup>. At 25 V of the applied voltage, the luminous brightness of about 500 cd/m<sup>2</sup> is obtained.

#### Example 7

In Example 6, a carrier transport layer is formed by a vacuum deposition. The deposition process is carried out by an apparatus having two deposition source crucibles as shown in Fig.15. The carrier transport layer is formed with a polyimide (BPDA-Phn) by depositing BPDA and SDA-n. BPDA is put in the first crucible and the following diamine compound (SDA-n) is put in the second crucible. The following 4 kinds to the polyimide layer is formed and tested



A base plate 201 provided with a transparent electroconductive electrode 202 is set at a base plate temperature of 50 °C and placed in a vacuum apparatus. Each crucible temperature is controlled to adjust each depositing rate to be equal. After forming the layer, a polyamic acid polymer as a precursor of the polyimide is heated to more than 250°C and subjected to imidation and crystallization treatment.

An organic light emitting layer 204 is laminated with Alq<sub>3</sub> in a same vacuum depositing as Example 6.

Fig. 16 shows a current-luminous brightness characteristic as to the resultant 4 kinds of organic light emitting devices. The reason that the polyimide of the above formula wherein n is odd has a superior property is caused by the crystallinity. In the case of BPDA-Ph3 indicating a best property, even a film formed by a polymer coating method can improve the property. That is, at a current density of 10mA/cm<sup>2</sup>, there is obtained a light emitting brightness of 100 cd/m<sup>2</sup>, which indicates a luminous efficiency having an order of magnitude larger.

#### Example 8

A organic light emitting device having an organic light receiving layer is prepared to have a memory property. Fig.3 shows the device structure. In the structure, as a lower electrode 302, ITO is formed on a glass base plate and then BPDA-Ph3 is laminated by 2 μm thereon as a light receiving layer 303. A light emitting layer is made of 1,1,4,4-tetra-phenyl-1,3-butadiene having a luminous peak wavelength of 430nm. The sensitive region of BPDA-Ph3 is less than 550nm. Therefore, it does not meet to the luminous peak of Alq<sub>3</sub> (550nm). As a melting point of a carrier transport layer 305 is less than 100°C, it is made of a depositing film (50 nm) of triphenylamine derivative (N,N'-diphenyl-N,N'-(3-methylphenyl)-1,1'-biphenyl-4,4'-diamine:TAD) in the place of BPDA-Ph3. A transparent electrode 306 is formed at a room temperature by ITO.

Fig.17 shows an applied voltage -luminous brightness characteristic. The brightness property shows hysteresis.

That is, at 40 V of applied voltage it comes to be in a light emitting condition and keep such a light emitting condition until less than 20 V of applied voltage.

Fig.18 shows a luminous property to a pulse applied voltage. When 45 V comprising + 15 V of pulse height and 30 V of bias voltage is applied, a luminous brightness of 150 cd/m<sup>2</sup> is obtained. After a pulse voltage is lost, light emitting is maintained. On the other hand, when pulse height is -15 V, the applied voltage is 15 V and quenching begins. Thereby, until a pulse is applied, a condition can be maintained and it means to realize the light emitting device having a memory ability.

#### Example 9

A light emitting type spatial modulator device is prepared. The device structure is the same as in Example 8. In this case, a light receiving layer 303 is written by an incident light from a glass base plate 301. Therefore, an output light from a light emitting layer 304 is not needed to be absorbed, the layer is made of Alq<sub>3</sub>. As the incident light, argon ion laser (488nm) is used. A change of luminous brightness to an intensity of incident light is shown in Fig.19. It shows non-linear property. Therefore, it is available to an optical threshold device. In this case, as the device has not a memory property, light emits only by incident light. On the other hand, if a light emitting layer 304 is made of the same as Example 3. That is, at the part which is written by a light to be in a light emitting state, the light emitting state is maintained after any incident light is lost. Fig.20 shows the change thereof. When incident light is irradiated at 35 V of the applied voltage, the voltage of the light receiving layer drops and thus an electric field concentrates into the light emitting layer 304 and the carrier transparent layer 305, thereby the device comes to be in a light emitting state. Without incident light, the receiving layer keeps a low resistant condition by means of irradiation from the light emitting layer and thus a light emitting state is maintained. On the other hand, when the applied voltage becomes less than 5 V, quenching begins and such a state is maintained even if the applied voltage returns to the primary voltage of 35 V, because the light receiving layer comes to be in a high resistance.

#### Example 10

An optical neural network system of Fig.12 is constituted by using the light emitting device of Example 9 and a test for its function and operation is carried out. The device structure is shown in Fig.11. The system is operated on the basis of an orthogonal learning method and is constituted of an incident picture 111 comprising the light emitting device of Example 8, a microlens array 112, learning mask pattern 113 and an optical threshold device 114 of Example 9. The input picture 111 has a matrix of 7x8 and can indicate 26 words of alphabet. As a picture input, a memory ability is used and each picture element is electrically written. The learning mask pattern 113 comprises a matrix of 49x64 and is made of a film having a variety of transmissivity in order to indicate 8 gradients depending on the intensity of transmitted light. The light threshold device 114 comprises a matrix of 7x8, in which a transmitted light is condensed from 7x8 of mask patterns to each picture element through the microlens array 113. The light emitting is made according to a light non-linear property shown in Fig.19. The system make answers with a recognition rate of 100% to an association of pattern provided alphabet 26 words.

As explained above, according to the embodiment of the present invention, a picture indication device comprising a light emitting device having a carrier transport layer and a light receiving layer containing a polymer comprising a repeating unit of the formula (II) make it possible to realize a high brightness display provided with a long life and stable driving at a low voltage and also realize a spatial light modulator having an ability of light-writing by means of light irradiation from outside. Therefore, the device is preferred to an optical computing system including an optical neural network system as a representative device or system.

#### Claims

1. A light-emitting device comprising an organic light-emitting layer (103; 204; 304) between a pair of electrodes (102, 104; 202, 205; 302, 306) mounted on a base plate (101; 201; 301),  
characterized in that the light-emitting layer (103; 204; 304) contains a polymer comprising a repeating unit of the formula



wherein n is at least 2; X is O, S, Se or Te; Y is an aromatic or substituted aromatic group; and Z is a group containing an imide ring.

2. The device of claim 1, characterized by further comprising a carrier transport layer (203; 305) between said pair of electrodes (102, 104; 202, 205; 302, 306).

3. The device of claim 2, characterized by further comprising a light receiving layer (303) between said pair of electrodes (102, 104; 202, 205; 302, 306).

4. The device of claim 2 or 3, characterized in that the carrier transport layer (203; 305) and/or the light receiving layer (303) are a layer of a polymer comprising a repeating unit of the following formula



wherein n is at least 2; X is O, S, Se or Te; and Y is an aromatic or substituted aromatic group.

5. Use of the device of anyone of the preceding claims for a light spatial modulator or a light neural system.

6. A process for preparing a light-emitting device comprising an organic light-emitting layer

characterized in that

a polymer comprising a repeating unit of the formula



wherein n is at least 2; X is O, S, Se or Te; Y is an aromatic or substituted aromatic group; and Z is a group containing an imide ring;

is laminated on a lower electrode (101; 201; 301) and formed as a light-emitting layer (103; 204; 304) by means of a gas-liquid boundary developing growth method.

#### Patentansprüche

1. Lichtemittierendes Bauelement mit einer organischen lichtemittierenden Schicht (103; 204; 304) zwischen einem Paar Elektroden (102, 104; 202, 205; 302, 306), die auf einer Grundplatte (101; 201; 301) angebracht sind, **dadurch gekennzeichnet**, daß die lichtemittierende Schicht (103; 204; 304) ein Polymer enthält, welches eine Wiederholungseinheit der Formel



enthält, wobei n mindestens den Wert 2 hat; X die Bedeutung O, S, Se oder Te hat; Y eine aromatische oder substituierte aromatische Gruppe bedeutet; und Z eine Gruppe bedeutet, die einen Imidring enthält.

2. Bauelement nach Anspruch 1, dadurch gekennzeichnet, daß es außerdem zwischen dem Paar Elektroden (102, 104; 202, 205; 302, 306) eine Ladungstransportschicht (203; 305) aufweist.

3. Bauelement nach Anspruch 2, dadurch gekennzeichnet, daß es außerdem zwischen dem Paar Elektroden (102, 104; 202, 205; 302, 306) eine lichtempfangende Schicht (303) aufweist.

4. Bauelement nach Anspruch 2 oder 3, dadurch gekennzeichnet, daß die Ladungstransportschicht (203; 305) und/oder die lichtempfangende Schicht (303) eine Schicht aus einem Polymer ist, welches eine Wiederholungseinheit der folgenden Formel



enthält, wobei n mindestens den Wert 2 hat; X die Bedeutung O, S, Se oder Te hat; und Y eine aromatische oder substituierte aromatische Gruppe bedeutet.

5. Verwendung des Bauelementes gemäß einem der vorhergehenden Ansprüche für einen Raumlichtmodulator oder ein neuronales Lichtsystem.

6. Verfahren zum Herstellen eines lichtemittierenden Bauelementes, welches eine organische lichtemittierende Schicht aufweist, **dadurch gekennzeichnet**, daß man ein Polymer, welches eine Wiederholungseinheit der Formel



aufweist, wobei n mindestens den Wert 2 hat; X die Bedeutung O, S, Se oder Te hat; Y eine aromatische oder substituierte aromatische Gruppe bedeutet; und Z eine Gruppe bedeutet, die einen Imidring enthält; mit Hilfe eines Wachstumsverfahrens an einer gas/flüssig-Grenzschicht auf eine untere Elektrode (101; 201; 301) auflaminiert und als lichtemittierende Schicht (103; 204; 304) ausbildet.

## Revendications

1. Dispositif photoémissif comprenant une couche organique photoémissive (103 ; 204 ; 304) placée entre deux électrodes (102, 104 ; 202, 205 ; 302, 306) montées sur une plaque de base (101 ; 201 ; 301),

caractérisé en ce que  
la couche photoémissive (103 ; 204 ; 304) contient un polymère ayant un motif répétitif de formule



n étant égal à 2, x étant O, S, Se ou Te, Y étant un groupe aromatique substitué ou non et Z étant un groupe à noyau imide.

2. Dispositif selon la revendication 1, caractérisé en ce qu'il comprend en outre une couche de transport de porteurs (203 ; 305) placée entre les deux électrodes (102, 104 ; 202, 205 ; 302, 306).
3. Dispositif selon la revendication 2, caractérisé en ce qu'il comprend en outre une couche photoréceptrice (303) placée entre les deux électrodes (102, 104 ; 202, 205 ; 302, 306).
4. Dispositif selon la revendication 2 ou 3, caractérisé en ce que la couche de transport de porteurs (203 ; 305) et/ou la couche photoréceptrice (303) sont formées d'un polymère comprenant un motif répétitif de formule suivante



n étant au moins égal à 2, X étant O, S, Se ou Te et Y étant un groupe aromatique substitué ou non.

5. Application du dispositif selon l'une quelconque des revendications précédentes à un modulateur spatial de lumière ou un circuit neuronal lumineux.

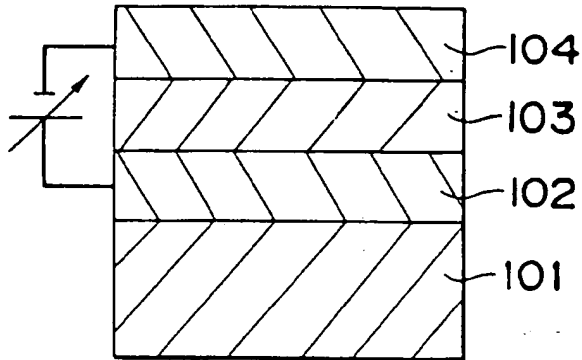
6. Procédé de préparation d'un dispositif photoémissif comprenant une couche organique photoémissive,

caractérisé en ce que  
un polymère comprenant un motif répétitif de formule

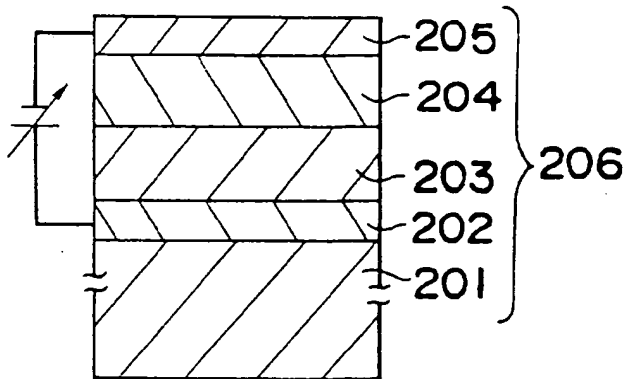


n étant au moins égal à 2, X représentant O, S, Se ou Te, Y étant un groupe aromatique substitué ou non et Z étant un groupe contenant un noyau imide, est placé sur une électrode inférieure (101 ; 201 ; 301) et forme une couche photoémissive (103 ; 204 ; 304) par un procédé de croissance par développement à une limite gaz-liquide.

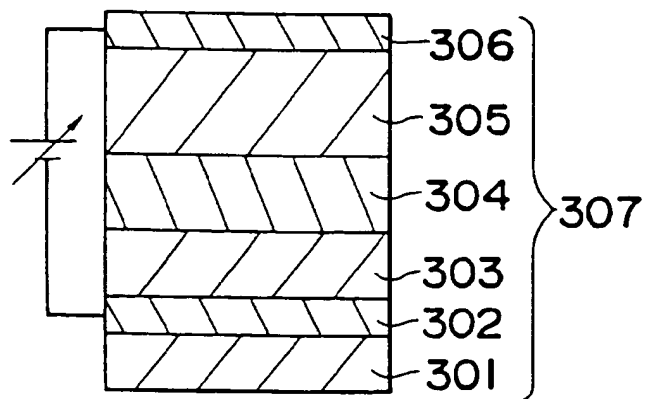
*Fig. 1*



*Fig. 2*

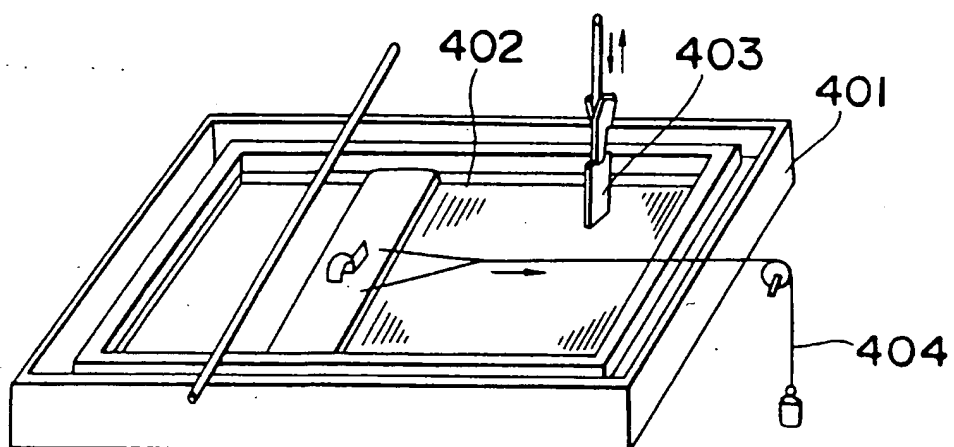


*Fig. 3*

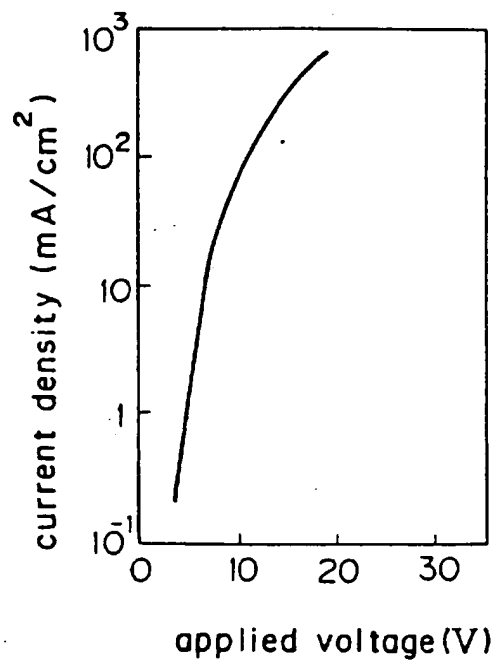




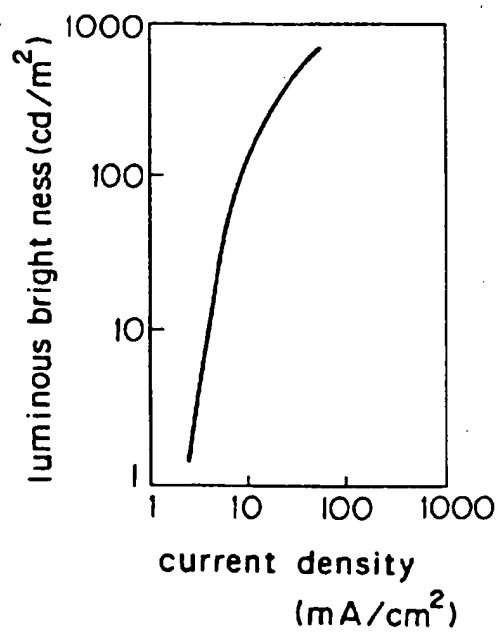
*Fig. 4*



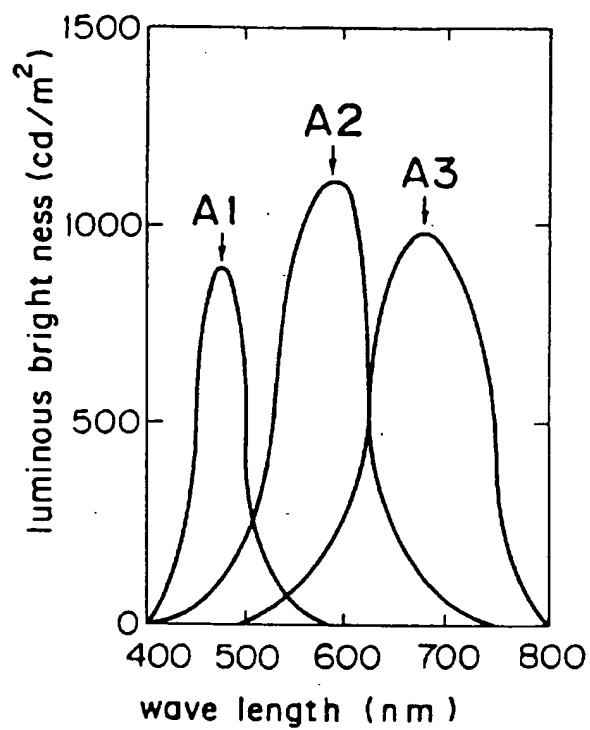
*Fig. 5*



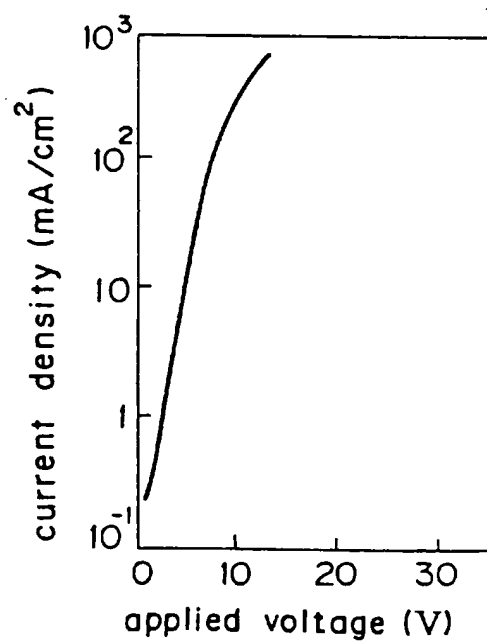
*Fig. 6*



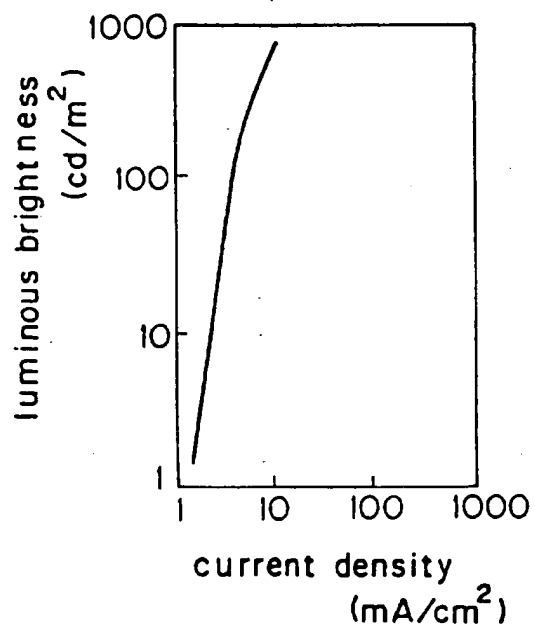
*Fig. 7*



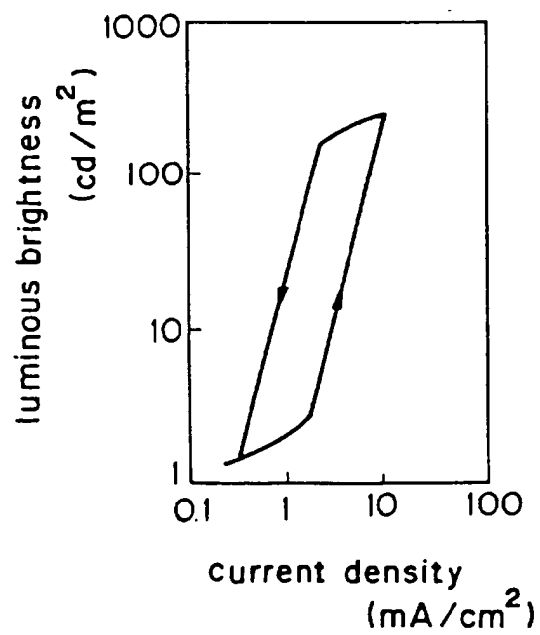
*Fig. 8*



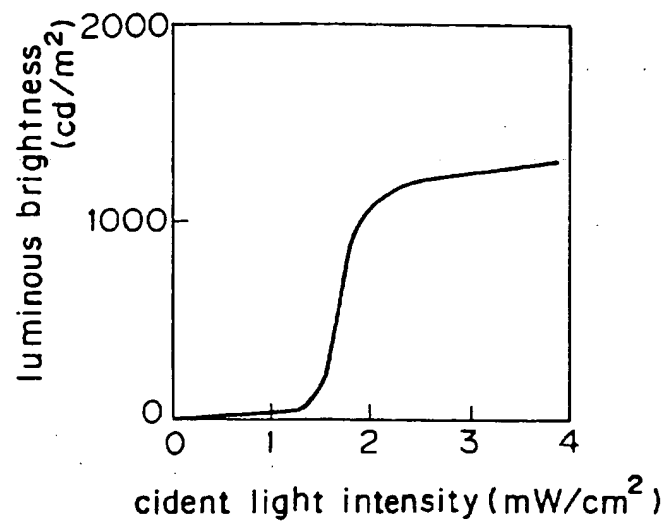
*Fig. 9*



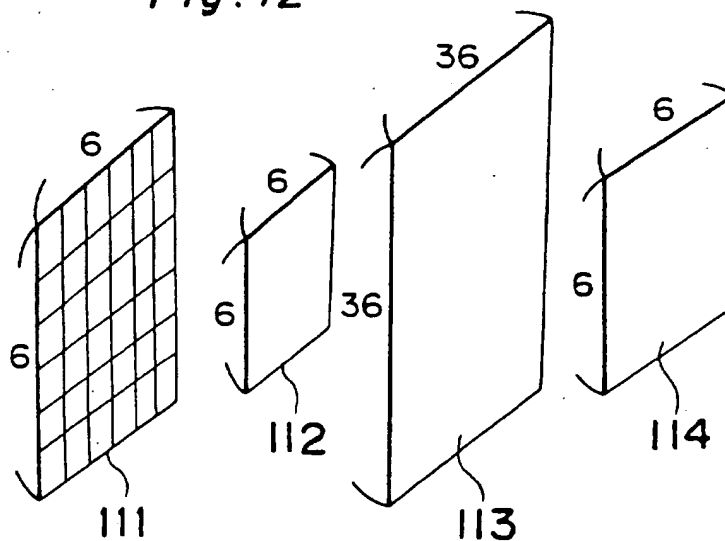
*Fig. 10*



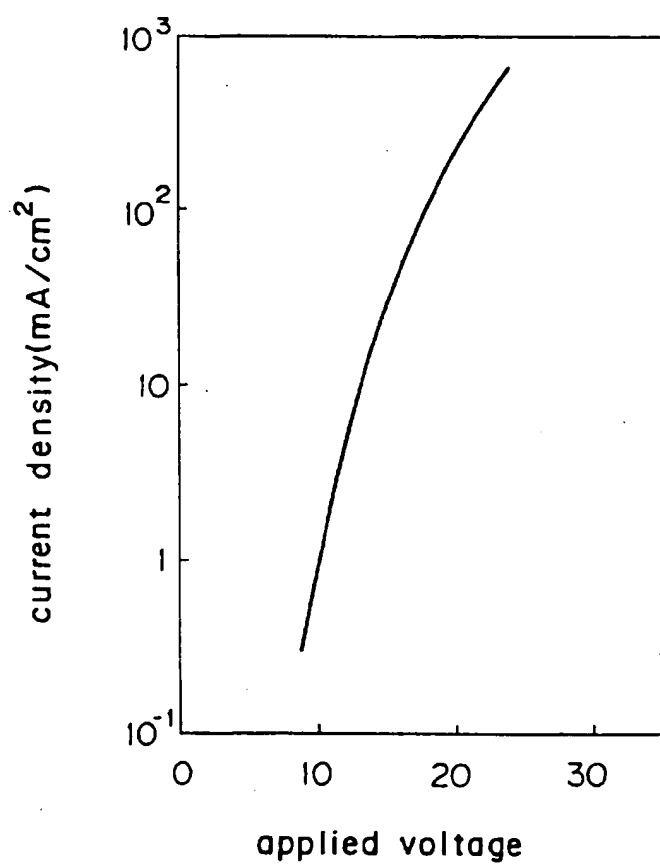
*Fig. 11*



*Fig. 12*



*Fig. 13*



*Fig. 14*

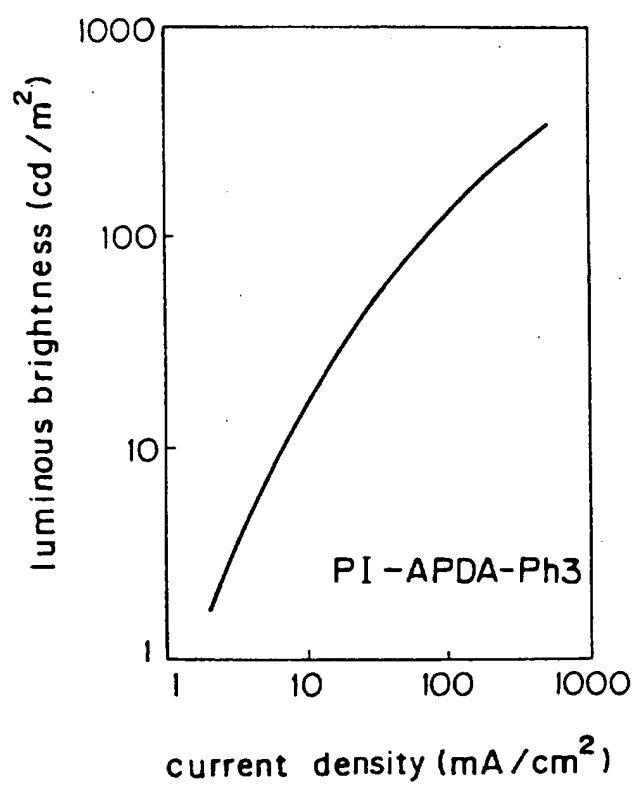
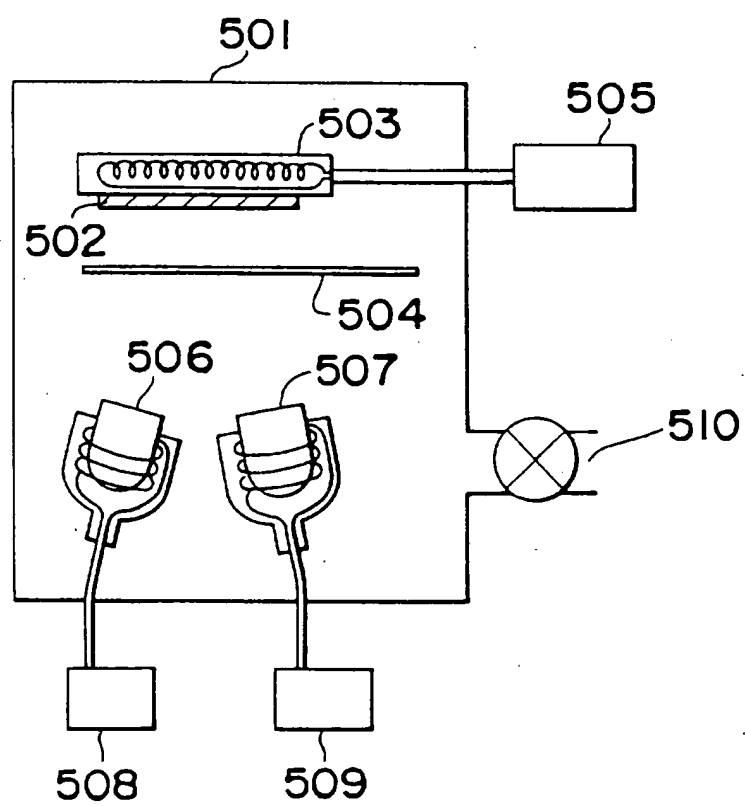


Fig. 15





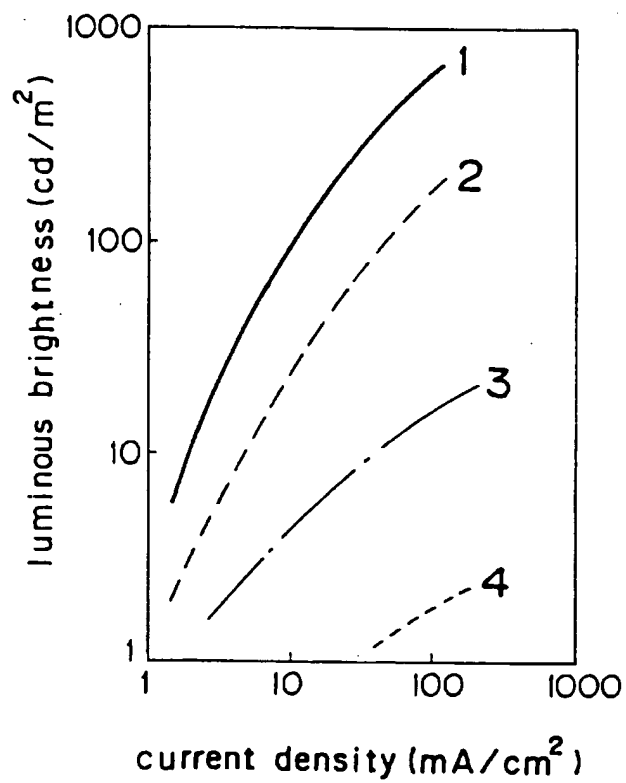
*Fig. 16*

1...BPDA-Ph 5

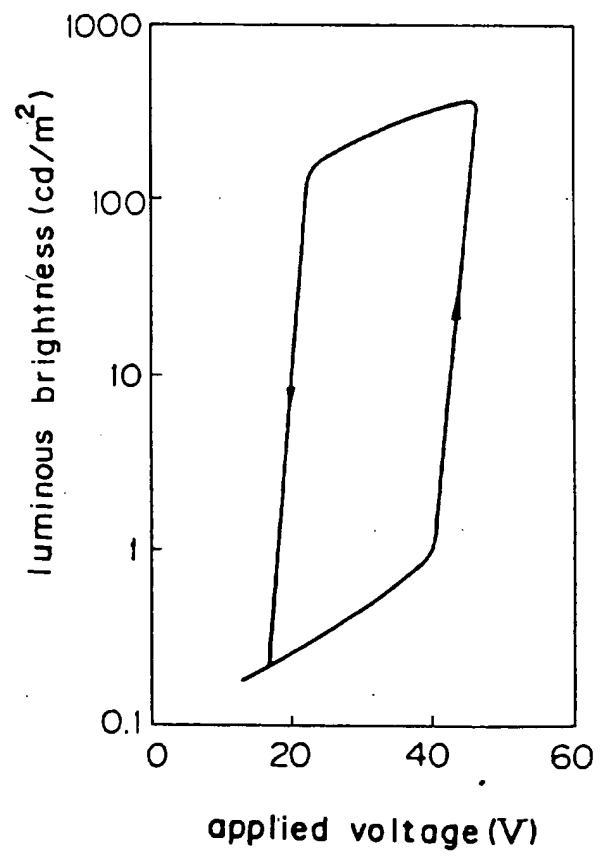
2...BPDA-Ph 3

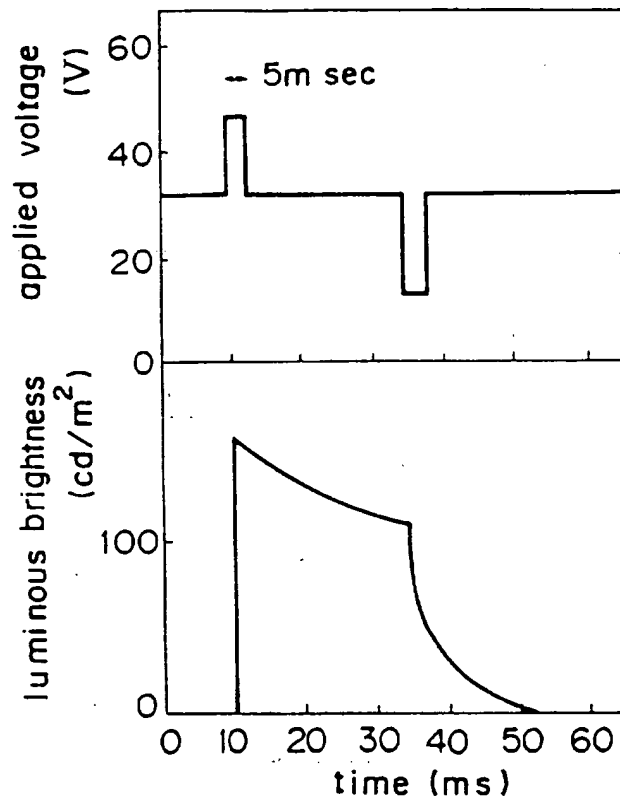
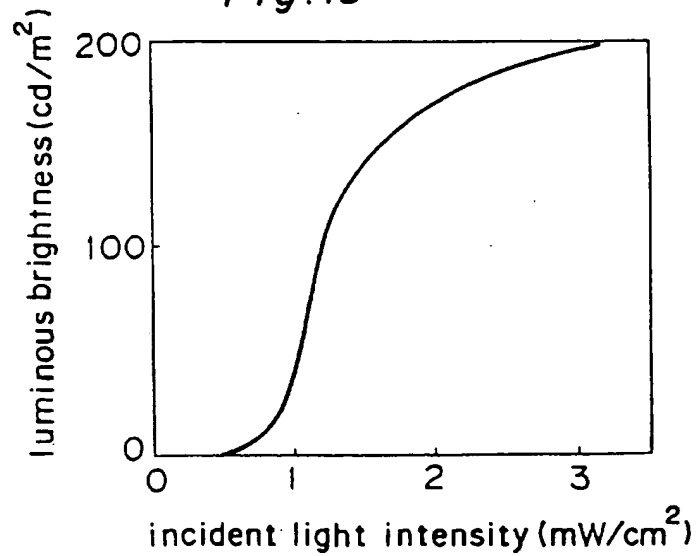
3...BPDA-Ph 4

4...BPDA-Ph 2



*Fig. 17*



*Fig. 18**Fig. 19*

*Fig. 20*

